

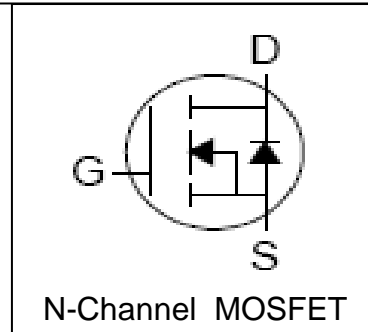
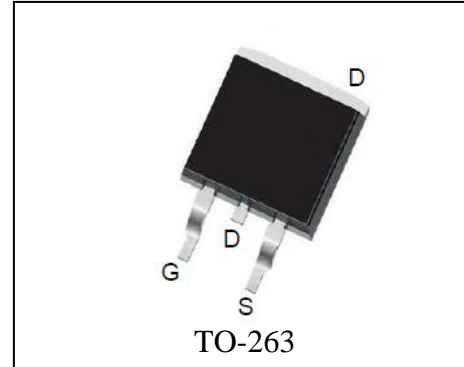
Features

- 80V/190A
 $R_{DS(ON)}=3.9m\Omega(Typ.) @ V_{GS}=10V$
- Avalanche Rated
- Reliable and Rugged
- Lead Free and Green Devices Available

Applications

- Automotive applications and a wide variety of other applications
- High Efficiency Synchronous in SMPS
- High Speed Power Switching

Pin Description



Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
Common Ratings ($T_A=25^\circ\text{C}$ Unless Otherwise Noted)			
V_{DSS}	Drain-Source Voltage	80	V
V_{GSS}	Gate-Source Voltage	± 25	
T_J	Maximum Junction Temperature	175	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-55 to 175	$^\circ\text{C}$
I_S	Diode Continuous Forward Current	$T_C=25^\circ\text{C}$ 190 ^①	A
Mounted on Large Heat Sink			
I_{DP}	300 μs Pulsed Drain Current Tested	$T_C=25^\circ\text{C}$ 700 ^②	A
I_D	Continue Drain Current	$T_C=25^\circ\text{C}$ 190 ^①	
		$T_C=100^\circ\text{C}$ 140 ^①	
P_D	Maximum Power Dissipation	$T_C=25^\circ\text{C}$ 312	W
		$T_C=100^\circ\text{C}$ 156	
$R_{\theta JC}$	Thermal Resistance -Junction to Case	0.48	$^\circ\text{C}/\text{W}$
Drain-Source Avalanche Ratings			
E_{AS} ^③	Avalanche Energy ,Single Pulsed	1225	mJ

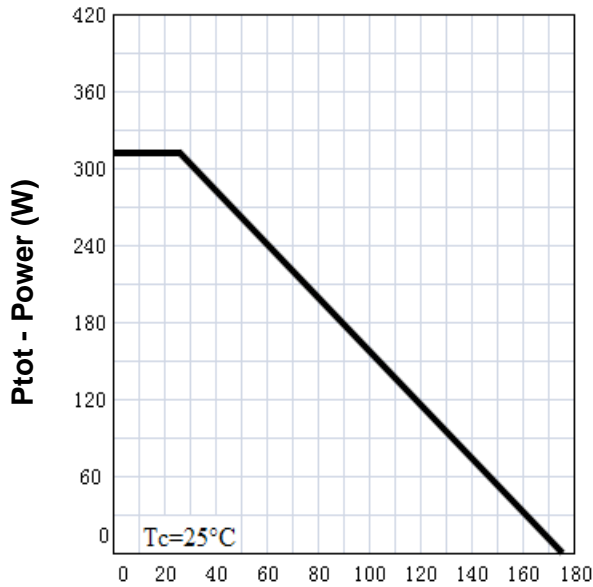
Electrical Characteristics ($T_A=25^{\circ}\text{C}$ Unless Otherwise Noted)

Symbol	Parameter	Test Condition	RU190N08S			Unit
			Min.	Typ.	Max.	
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_{DS}=250\mu A$	80			V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=80V, V_{GS}=0V$ $T_J=85^{\circ}\text{C}$			1	μA
					30	
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_{DS}=250\mu A$	2	3	4	V
I_{GSS}	Gate Leakage Current	$V_{GS}=\pm 25V, V_{DS}=0V$			± 100	nA
$R_{DS(ON)}^{(4)}$	Drain-Source On-state Resistance	$V_{GS}=10V, I_{DS}=40A$		3.9	4.8	m Ω
Diode Characteristics						
$V_{SD}^{(4)}$	Diode Forward Voltage	$I_{SD}=40A, V_{GS}=0V$			1.2	V
t_{rr}	Reverse Recovery Time	$I_{SD}=40A, dI_{SD}/dt=100A/\mu s$		68		ns
q_{rr}	Reverse Recovery Charge			130		nC
Dynamic Characteristics ⁽⁵⁾						
R_G	Gate Resistance	$V_{GS}=0V, V_{DS}=0V, F=1\text{MHz}$		1.0		Ω
C_{iss}	Input Capacitance	$V_{GS}=0V,$ $V_{DS}=30V,$ Frequency=1.0MHz		6800		pF
C_{oss}	Output Capacitance			1100		
C_{riss}	Reverse Transfer Capacitance			490		
$t_{d(ON)}$	Turn-on Delay Time	$V_{DD}=35V, R_L=35\Omega,$ $I_{DS}=1A, V_{GEN}=10V,$ $R_G=6\Omega$		38		ns
t_r	Turn-on Rise Time			22		
$t_{d(OFF)}$	Turn-off Delay Time			120		
t_f	Turn-off Fall Time			75		
Gate Charge Characteristics ⁽⁵⁾						
Q_g	Total Gate Charge	$V_{DS}=30V, V_{GS}=10V,$ $I_{DS}=40A$		155		nC
Q_{gs}	Gate-Source Charge			45		
Q_{gd}	Gate-Drain Charge			48		

- Notes:
- ① Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 75A.
 - ② Pulse width limited by safe operating area.
 - ③ Limited by T_{Jmax} , $I_{AS}=50A$, $V_{DD}=48V$, $R_G=47\Omega$, Starting $T_J=25^{\circ}\text{C}$.
 - ④ Pulse test; Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
 - ⑤ Guaranteed by design, not subject to production testing.

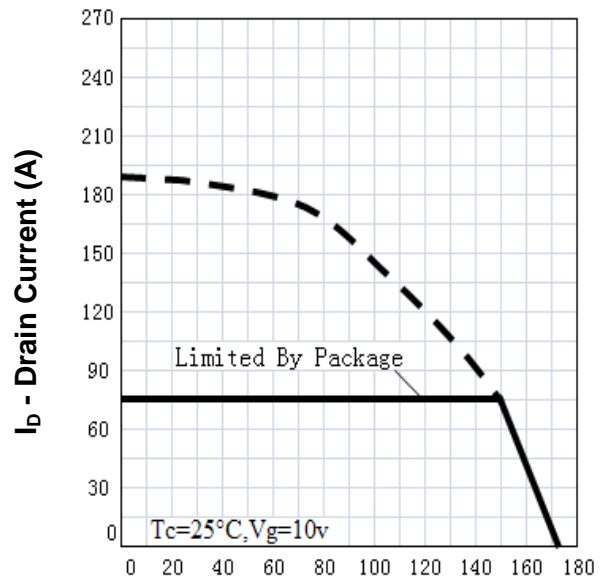
Typical Characteristics

Power Dissipation



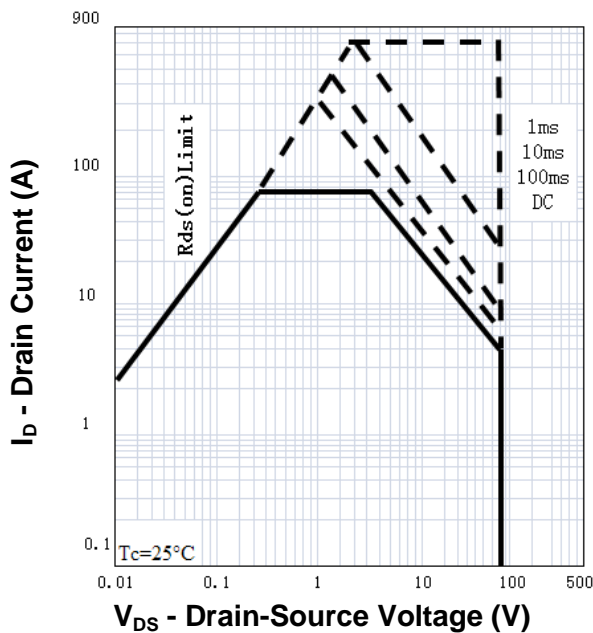
T_j - Junction Temperature ($^{\circ}C$)

Drain Current

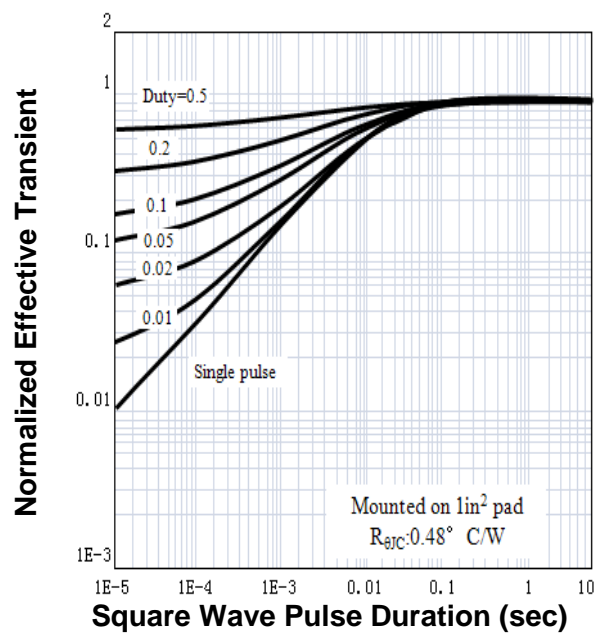


T_j - Junction Temperature ($^{\circ}C$)

Safe Operation Area

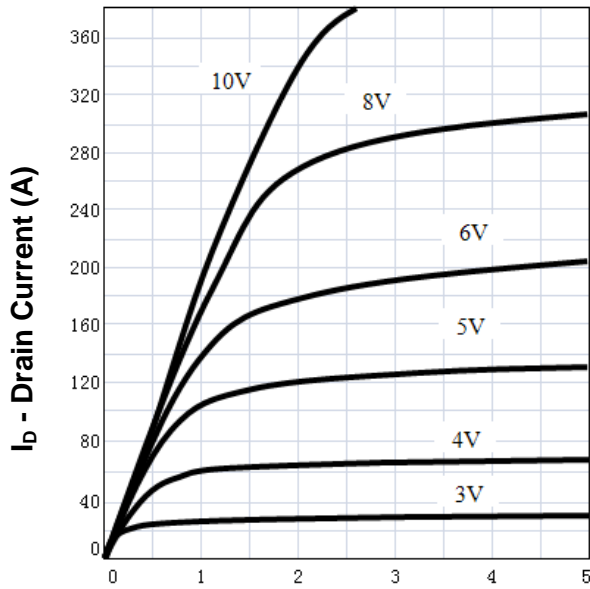


Thermal Transient Impedance



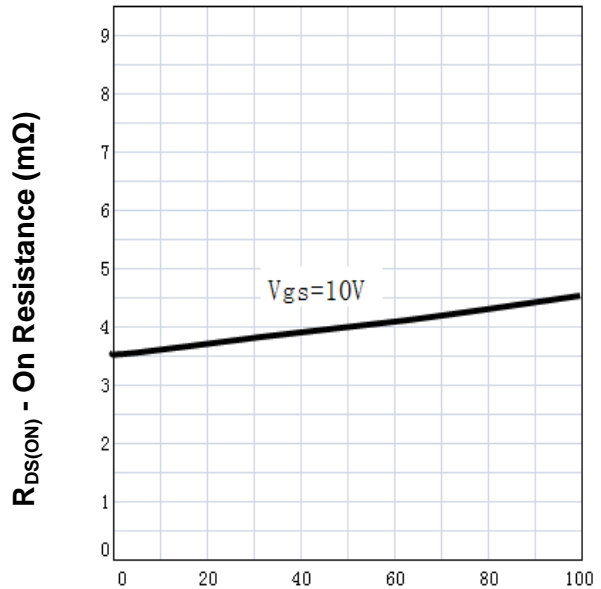
Typical Characteristics

Output Characteristics



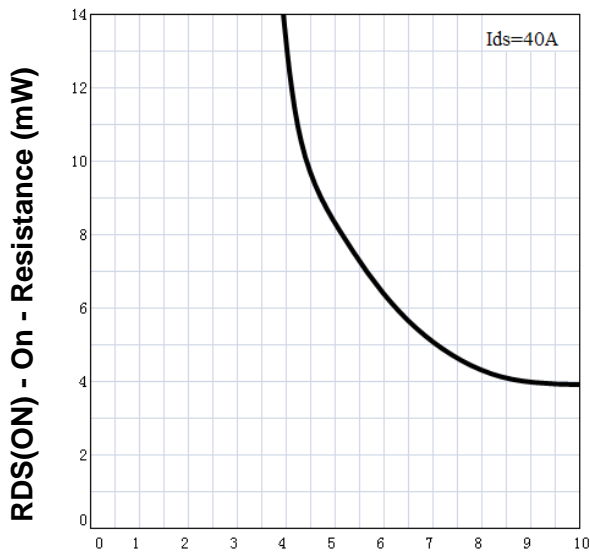
V_{DS} - Drain-Source Voltage (V)

Drain-Source On Resistance



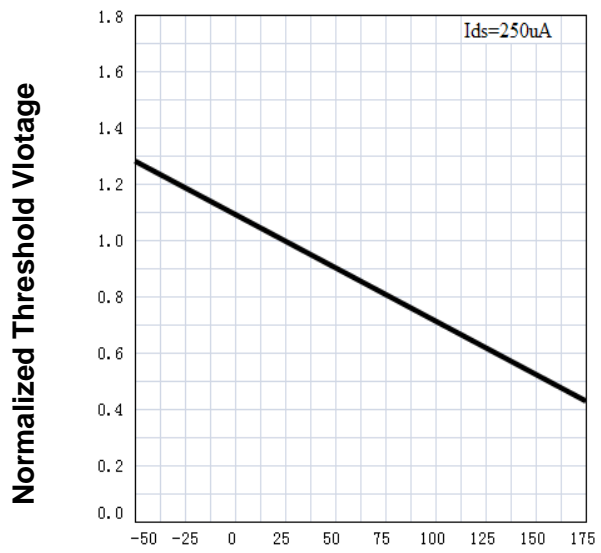
I_D - Drain Current (A)

Drain-Source On Resistance



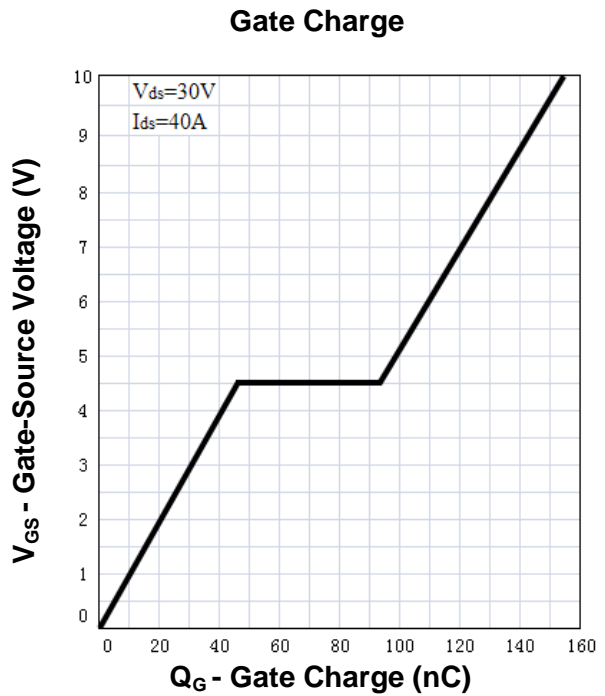
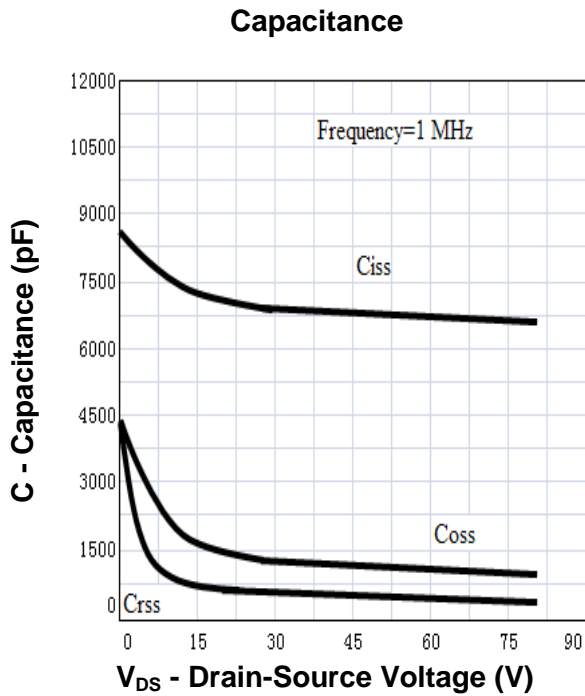
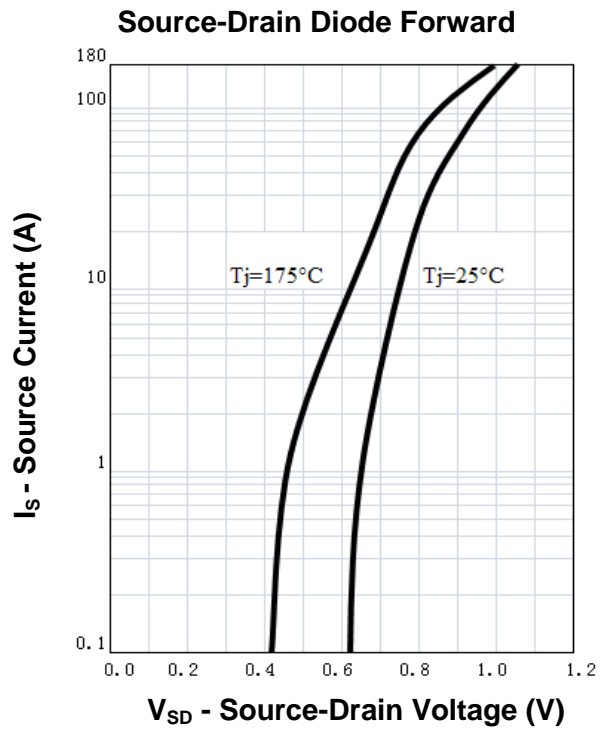
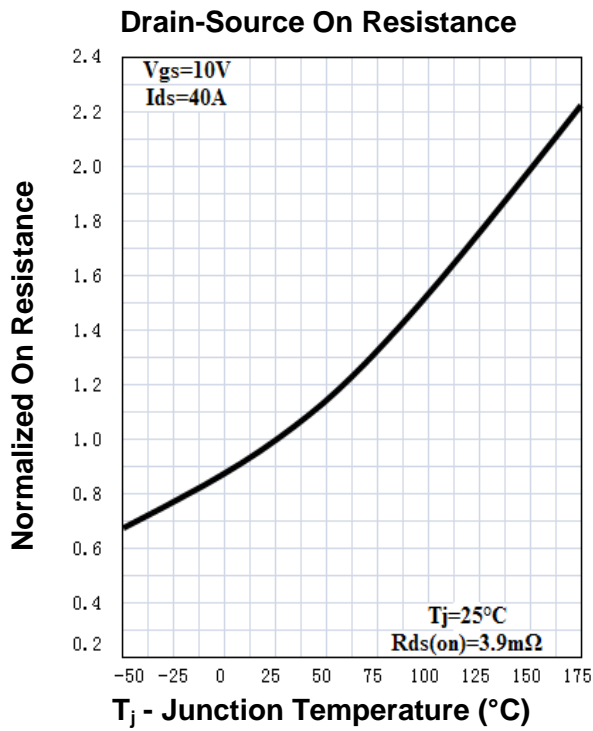
V_{GS} - Gate - Source Voltage (V)

Gate Threshold Voltage

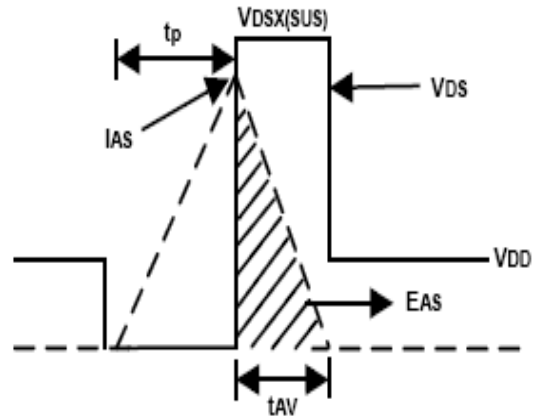
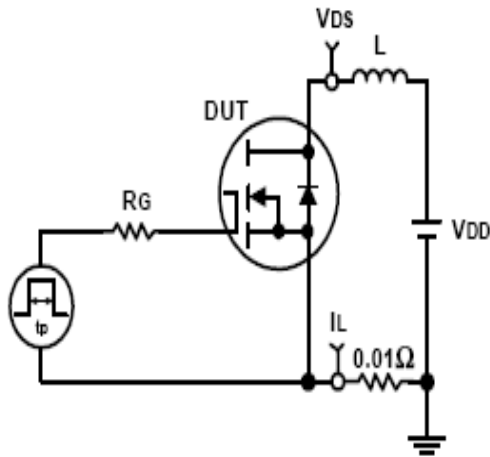


T_j - Junction Temperature ($^{\circ}C$)

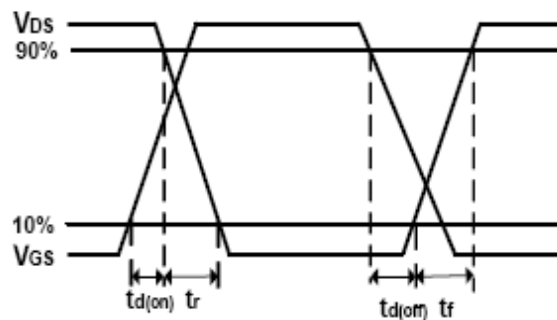
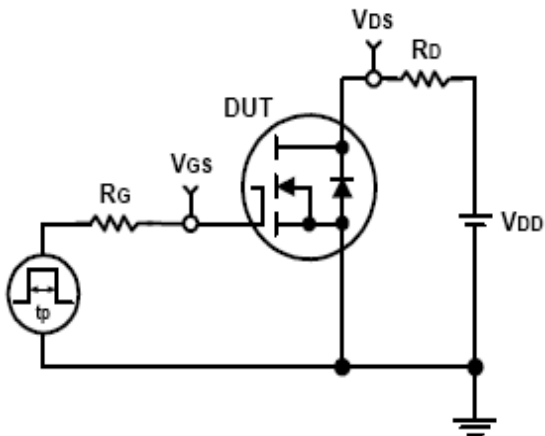
Typical Characteristics



Avalanche Test Circuit and Waveforms



Switching Time Test Circuit and Waveforms

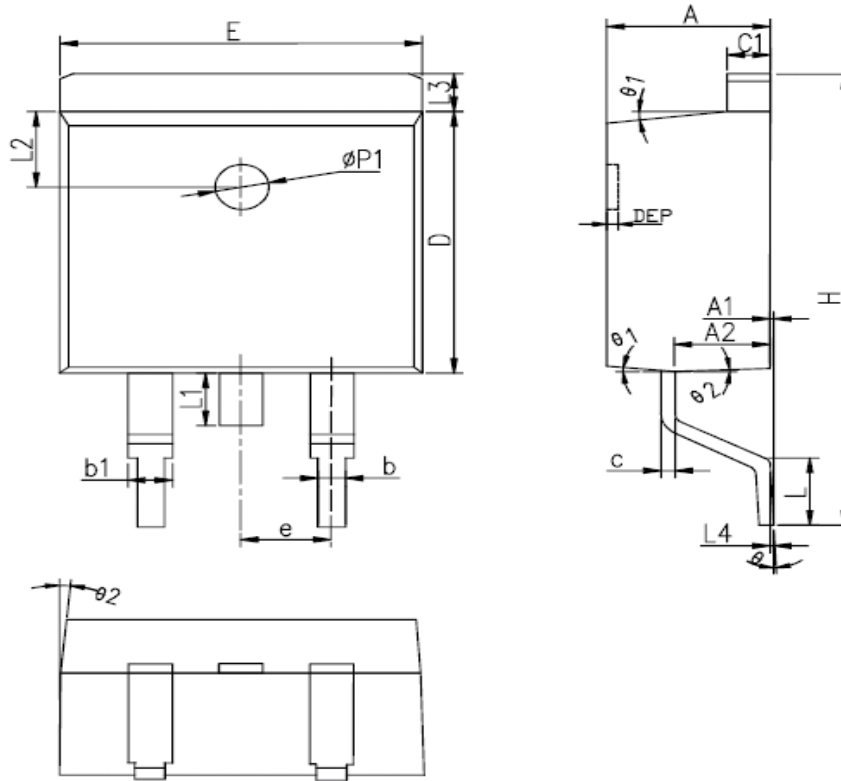


Ordering and Marking Information

Device	Marking	Package	Packaging	Quantity	Reel Size	Tape width
RU190N08S	RU190N08S	TO-263	Tube	50	-	-
RU190N08S-R	RU190N08S	TO-263	Tape&Reel	800	13''	24mm

Package Information

TO-263-2L



SYMBOL	MM			INCH			SYMBOL	MM			INCH		
	MIN	NOM	MAX	MIN	NOM	MAX		MIN	NOM	MAX	MIN	NOM	MAX
A	4.40	4.57	4.70	0.173	0.180	0.185	L	2.00	2.30	2.60	0.079	0.090	0.102
A1	0	0.10	0.25	0	0.004	0.010	L3	1.17	1.27	1.40	0.046	0.050	0.055
A2	2.59	2.69	2.79	0.102	0.106	0.110	L1	-	-	1.70	-	-	0.067
b	0.77	-	0.90	0.030	-	0.035	L4	0.25BSC			0.01BSC		
b1	1.23	-	1.36	0.048	-	0.052	L2	2.50REF.			0.098REF.		
c	0.34	-	0.47	0.013	-	0.019	Ø	0°	-	8°	0°	-	8°
C1	1.22	-	1.32	0.048	-	0.052	Ø 1	5°	7°	9°	5°	7°	9°
D	8.60	8.70	8.80	0.338	0.343	0.346	Ø 2	1°	3°	5°	1°	3°	5°
E	10.00	10.16	10.26	0.394	0.4	0.404	DEP	0.05	0.10	0.20	0.002	0.004	0.008
e	2.54BSC			0.1BSC			Øp1	1.40	1.50	1.60	0.055	0.059	0.063
H	14.70	15.10	15.50	0.579	0.594	0.610							

**ALL DIMENSIONS REFER TO JEDEC STANDARD
DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS**

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